

Programmable Quad Operational Amplifiers

GENERAL DESCRIPTION

The XR-146 family of quad operational amplifiers contain four independent high-gain, low-power, programmable op-amps on a monolithic chip. The use of external bias setting resistors permit the user to program gain-bandwidth product, supply current, input bias current, input offset current, input noise and the slew rate.

The basic XR-146 family of circuits offer partitioned programming of the internal op-amps where one setting resistor is used to set the bias levels in the three op-amps, and a second bias setting is used for the remaining op-amp.

FEATURES

- Programmable
- Micropower operation
- Low noise
- Wide power supply range
- Class AB output
- Ideal pin out for biquad active filters
- Overload protection for input and output
- Internal frequency compensation

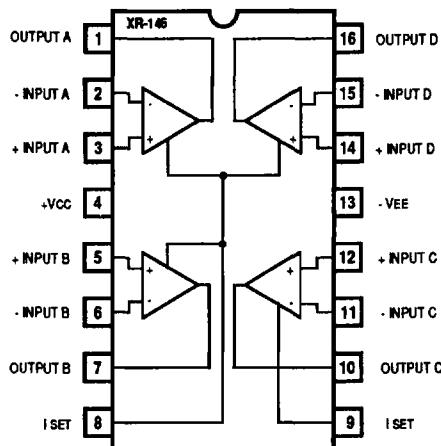
APPLICATIONS

- Total Supply Current = 1.4 mA ($I_{SET}/10 \mu\text{A}$)
- Gain Bandwidth Product = 1 MHz ($I_{SET}/10 \mu\text{A}$)
- Slew Rate = $0.4\text{V}/\mu\text{s}$ ($I_{SET}/10 \mu\text{A}$)
- Input Bias Current $\sim 50 \text{nA}$ ($I_{SET}/10 \mu\text{A}$)

I_{SET} = Current into pin 8, pin 9 (see schematic)

$$I_{SET} = \frac{V^+ - V^- - 0.6V}{R_{SET}}$$

FUNCTIONAL BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

Supply Voltage XR-146	$\pm 22\text{V}$
Differential Input Voltage XR-146	$\pm 30\text{V}$
Common Mode Input Voltage XR-146	$\pm 15\text{V}$
Power Dissipation XR-146	900 mW
Output Short Circuit Duration XR-146	Indefinite
Maximum Junction Temperature XR-146	+150°C
Storage Temperature Range XR-146	-65°C to + 150°C

Rev-A

XR-146

ELECTRICAL PERFORMANCE CHARACTERISTICS - XR-146

TEST	SYMBOL	CONDITIONS	TEMPERATURE	MIN	LIMITS MAX	UNIT	GROUP A SUBGROUP
Supply Current	I _{CC}	V _s =±15V I _{SET} = 10µA	T _A = +25°C -55°C ≤ T _A ≤ +125°C	2.00	2.00	mA	1 2,3
Supply Current	I _{CC}	V _s = ±22V I _{SET} = 10µA	T _A = +25°C	4.00		mA	1
Input Offset Voltage	V _{os}	V _s =±15V, R _s =50Ω I _{SET} = 10µA	T _A = +25°C -55°C ≤ T _A ≤ +125°C	5.00	6.00	mV	1 2,3
Input Bias Current	I _b	V _s =±15V, R _s =10KΩ I _{SET} = 10µA	T _A = +25°C -55°C ≤ T _A ≤ +125°C	100	100	nA	1 2,3
Input Offset Current	I _{os}	V _s =±15V, R _s =100KΩ I _{SET} = 10µA	T _A = +25°C -55°C ≤ T _A ≤ +125°C	20	25	nA	1 2,3
Power Supply Rejection Ratio	PSRR	R _s = 10KΩ ±10V ≤ V _s ≤ ±15V	T _A = +25°C -55°C ≤ T _A ≤ +125°C	100	100	uV/V dB	1 2,3
Common Mode Rejection Ratio	CMRR	V _{CM} = ±13.5V V _s =±15V, R _L =10KΩ	T _A = +25°C -55°C ≤ T _A ≤ +125°C	80	70	dB	1 2,3
Large Signal Voltage Gain	AVO	V _o =±10V, R _s =50Ω V _s =±15V, R _L =10KΩ V _o =±10V V _s =±15V, R _L =10KΩ	T _A = +25°C -55°C ≤ T _A ≤ +125°C	100	50	V/mV	4 5,6
Output Voltage - Swing	V _o	R _L = 10KΩ V _s =±15V, R _s =125Ω V _s =±15V, R _L =10KΩ	T _A = +25°C -55°C ≤ T _A ≤ +125°C	±12	±12	V	4 5,6
Short Circuit Current	I _{sc}	V _s =±15V, R _s =50Ω	T _A = +25°C	5	30	mA	1
Supply Current	I _{cc}	V _s =±15V, I _{SET} =1µA	T _A = +25°C		250	µA	1
Input Offset Voltage	V _{os}	R _s = 50Ω, V _s =±15V I _{SET} = 1µA	T _A = +25°C		5.00	mV	1
Input Bias Current	I _b	R _s =10 KΩ, V _s =±15V I _{SET} = 1µA	T _A = +25°C		20	nA	1
Input Offset Voltage	V _{os}	R _s =50Ω, V _s =±15V I _{SET} = 10µA	T _A = +25°C		5.00	mV	1
Common Mode Rejection Ratio	CMRR	R _s = 50Ω, V _s = 1.5V V _{CM} = ±0.7V	T _A = +25°C	60		dB	1
Output Voltage - Swing	V _o	R _L =10KΩ, R _s =50Ω V _s =±1.5V,I _{SET} =10µA	T _A = +25°C	10.6		V	4